

## 110 $\mu$ A, High Precision Op Amps

### Features

- Low Offset Voltage:  $\pm 150 \mu\text{V}$  (maximum)
- Low Quiescent Current: 110  $\mu\text{A}$  (typical)
- Rail-to-Rail Input and Output
- Wide Supply Voltage Range: 1.8V to 6.0V
- Gain Bandwidth Product: 1.2 MHz (typical)
- Unity Gain Stable
- Extended Temperature Range:  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$
- No Phase Reversal

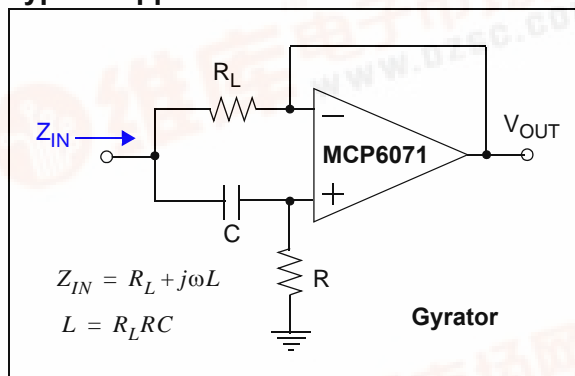
### Applications

- Automotive
- Portable Instrumentation
- Sensor Conditioning
- Battery Powered Systems
- Medical Instrumentation
- Test Equipment
- Analog Filters

### Design Aids

- SPICE Macro Models
- FilterLab<sup>®</sup> Software
- Mindi<sup>™</sup> Circuit Designer & Simulator
- MAPS (Microchip Advanced Part Selector)
- Analog Demonstration and Evaluation Boards
- Application Notes

### Typical Application



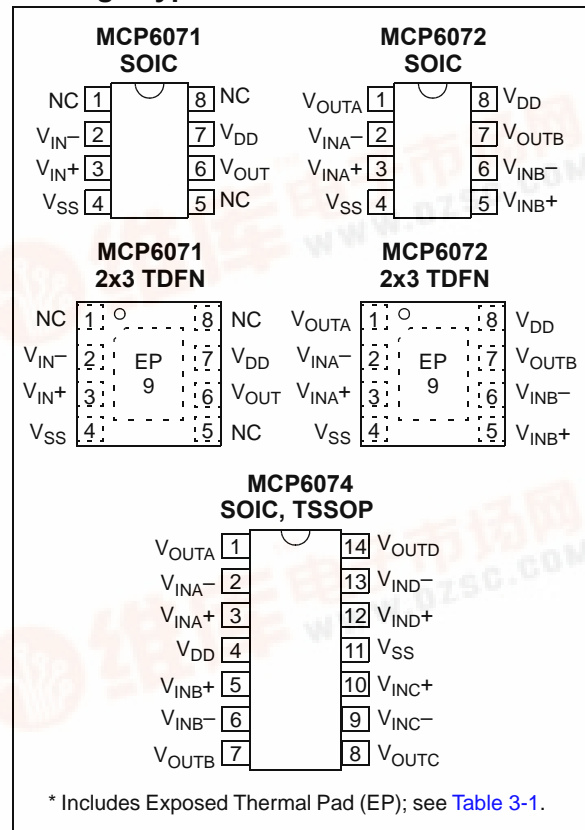
### Description

The Microchip Technology Inc. MCP6071/2/4 family of operational amplifiers (op amps) has low input offset voltage ( $\pm 150 \mu\text{V}$ , maximum) and rail-to-rail input and output operation. This family is unity gain stable and has a gain bandwidth product of 1.2 MHz (typical). These devices operate with a single supply voltage as low as 1.8V, while drawing low quiescent current per amplifier (110  $\mu\text{A}$ , typical). These features make the family of op amps well suited for single-supply, high precision, battery-powered applications.

The MCP6071/2/4 family is offered in single (MCP6071), dual (MCP6072), and quad (MCP6074) configurations.

The MCP6071/2/4 is designed with Microchip's advanced CMOS process. All devices are available in the extended temperature range, with a power supply range of 1.8V to 6.0V.

### Package Types



# MCP6071/2/4

---

[查询MCP6074供应商](#)

**NOTES:**

**1.0 ELECTRICAL CHARACTERISTICS****1.1 Absolute Maximum Ratings †**

$V_{DD} - V_{SS}$ .....	7.0V
Current at Input Pins .....	±2 mA
Analog Inputs ( $V_{IN+}$ , $V_{IN-}$ )†† .....	$V_{SS} - 1.0V$ to $V_{DD} + 1.0V$
All Other Inputs and Outputs .....	$V_{SS} - 0.3V$ to $V_{DD} + 0.3V$
Difference Input Voltage .....	$ V_{DD} - V_{SS} $
Output Short-Circuit Current .....	continuous
Current at Output and Supply Pins .....	±30 mA
Storage Temperature .....	-65°C to +150°C
Maximum Junction Temperature ( $T_J$ ) .....	+150°C
ESD protection on all pins (HBM; MM) .....	≥ 4 kV; 400V

† **Notice:** Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

†† See 4.1.2 “Input Voltage And Current Limits”

**1.2 Specifications****TABLE 1-1: DC ELECTRICAL SPECIFICATIONS**

<b>Electrical Characteristics:</b> Unless otherwise indicated, $V_{DD} = +1.8V$ to $+6.0V$ , $V_{SS} = GND$ , $T_A = +25^\circ C$ , $V_{CM} = V_{DD}/2$ , $V_{OUT} \approx V_{DD}/2$ , $V_L = V_{DD}/2$ and $R_L = 10\text{ k}\Omega$ to $V_L$ . (Refer to <a href="#">Figure 1-1</a> ).						
Parameters	Sym	Min	Typ	Max	Units	Conditions
<b>Input Offset</b>						
Input Offset Voltage	$V_{OS}$	-150	—	+150	$\mu V$	$V_{DD} = 3.0V$ , $V_{CM} = V_{DD}/3$
Input Offset Drift with Temperature	$\Delta V_{OS}/\Delta T_A$	—	±1.5	—	$\mu V/^\circ C$	$T_A = -40^\circ C$ to $+85^\circ C$ , $V_{DD} = 3.0V$ , $V_{CM} = V_{DD}/3$
	$\Delta V_{OS}/\Delta T_A$	—	±4.0	—	$\mu V/^\circ C$	$T_A = +85^\circ C$ to $+125^\circ C$ , $V_{DD} = 3.0V$ , $V_{CM} = V_{DD}/3$
Power Supply Rejection Ratio	PSRR	70	87	—	dB	$V_{CM} = V_{SS}$
<b>Input Bias Current and Impedance</b>						
Input Bias Current	$I_B$	—	±1.0	100	pA	$T_A = +85^\circ C$ $T_A = +125^\circ C$
	$I_B$	—	60	—	pA	
	$I_B$	—	1100	5000	pA	
Input Offset Current	$I_{OS}$	—	±1.0	—	pA	
Common Mode Input Impedance	$Z_{CM}$	—	$10^{13}  6$	—	$\Omega  pF$	
Differential Input Impedance	$Z_{DIFF}$	—	$10^{13}  6$	—	$\Omega  pF$	
<b>Common Mode</b>						
Common Mode Input Voltage Range	$V_{CMR}$	$V_{SS}-0.15$	—	$V_{DD}+0.15$	V	$V_{DD} = 1.8V$ ( <b>Note 1</b> )
	$V_{CMR}$	$V_{SS}-0.3$	—	$V_{DD}+0.3$	V	$V_{DD} = 6.0V$ ( <b>Note 1</b> )
Common Mode Rejection Ratio	CMRR	72	89	—	dB	$V_{CM} = -0.15V$ to $1.95V$ , $V_{DD} = 1.8V$
		74	91	—	dB	$V_{CM} = -0.3V$ to $6.3V$ , $V_{DD} = 6.0V$
		72	87	—	dB	$V_{CM} = 3.0V$ to $6.3V$ , $V_{DD} = 6.0V$
		74	89	—	dB	$V_{CM} = -0.3V$ to $3.0V$ , $V_{DD} = 6.0V$

**Note 1:** [Figure 2-13](#) shows how  $V_{CMR}$  changed across temperature.

# MCP6071/2/4

[查询MCP6074供应商](#)

**TABLE 1-1: DC ELECTRICAL SPECIFICATIONS (CONTINUED)**

<b>Electrical Characteristics:</b> Unless otherwise indicated, $V_{DD} = +1.8V$ to $+6.0V$ , $V_{SS} = GND$ , $T_A = +25^\circ C$ , $V_{CM} = V_{DD}/2$ , $V_{OUT} \approx V_{DD}/2$ , $V_L = V_{DD}/2$ and $R_L = 10\text{ k}\Omega$ to $V_L$ . (Refer to <a href="#">Figure 1-1</a> ).						
Parameters	Sym	Min	Typ	Max	Units	Conditions
<b>Open-Loop Gain</b>						
DC Open-Loop Gain (Large Signal)	$A_{OL}$	95	115	—	dB	$0.2V < V_{OUT} < (V_{DD}-0.2V)$ $V_{CM} = V_{SS}$
<b>Output</b>						
Maximum Output Voltage Swing	$V_{OL}, V_{OH}$	$V_{SS}+15$	—	$V_{DD}-15$	mV	$G = +2\text{ V/V}$ , 0.5V input overdrive
Output Short-Circuit Current	$I_{SC}$	—	$\pm 7$ $\pm 28$	—	mA mA	$V_{DD} = 1.8V$ $V_{DD} = 6.0V$
<b>Power Supply</b>						
Supply Voltage	$V_{DD}$	1.8	—	6.0	V	
Quiescent Current per Amplifier	$I_Q$	50	110	170	$\mu A$	$I_O = 0$ , $V_{DD} = 6.0V$ $V_{CM} = 0.9V_{DD}$

**Note 1:** [Figure 2-13](#) shows how  $V_{CMR}$  changed across temperature.

**TABLE 1-2: AC ELECTRICAL SPECIFICATIONS**

<b>Electrical Characteristics:</b> Unless otherwise indicated, $T_A = +25^\circ C$ , $V_{DD} = +1.8$ to $+6.0V$ , $V_{SS} = GND$ , $V_{CM} = V_{DD}/2$ , $V_{OUT} \approx V_{DD}/2$ , $V_L = V_{DD}/2$ , $R_L = 10\text{ k}\Omega$ to $V_L$ and $C_L = 60\text{ pF}$ . (Refer to <a href="#">Figure 1-1</a> ).						
Parameters	Sym	Min	Typ	Max	Units	Conditions
<b>AC Response</b>						
Gain Bandwidth Product	GBWP	—	1.2	—	MHz	
Phase Margin	PM	—	57	—	$^\circ$	$G = +1\text{ V/V}$
Slew Rate	SR	—	0.5	—	V/ $\mu s$	
<b>Noise</b>						
Input Noise Voltage	$E_{ni}$	—	4.3	—	$\mu V_{p-p}$	$f = 0.1\text{ Hz to }10\text{ Hz}$
Input Noise Voltage Density	$e_{ni}$	—	19	—	nV/ $\sqrt{\text{Hz}}$	$f = 10\text{ kHz}$
Input Noise Current Density	$i_{ni}$	—	0.6	—	fA/ $\sqrt{\text{Hz}}$	$f = 1\text{ kHz}$

**TABLE 1-3: TEMPERATURE SPECIFICATIONS**

<b>Electrical Characteristics:</b> Unless otherwise indicated, $V_{DD} = +1.8V$ to $+6.0V$ and $V_{SS} = GND$ .						
Parameters	Sym	Min	Typ	Max	Units	Conditions
<b>Temperature Ranges</b>						
Operating Temperature Range	$T_A$	-40	—	+125	$^\circ C$	<b>Note 1</b>
Storage Temperature Range	$T_A$	-65	—	+150	$^\circ C$	
<b>Thermal Package Resistances</b>						
Thermal Resistance, 8L-2x3 TDFN	$\theta_{JA}$	—	41	—	$^\circ C/W$	
Thermal Resistance, 8L-SOIC	$\theta_{JA}$	—	149.5	—	$^\circ C/W$	
Thermal Resistance, 14L-SOIC	$\theta_{JA}$	—	95.3	—	$^\circ C/W$	
Thermal Resistance, 14L-TSSOP	$\theta_{JA}$	—	100	—	$^\circ C/W$	

**Note 1:** The internal junction temperature ( $T_J$ ) must not exceed the absolute maximum specification of  $+150^\circ C$ .

[查询MCP6074供应商](#)

## 1.3 Test Circuits

The circuit used for most DC and AC tests is shown in [Figure 1-1](#). This circuit can independently set  $V_{CM}$  and  $V_{OUT}$ ; see [Equation 1-1](#). Note that  $V_{CM}$  is not the circuit's common mode voltage  $((V_P + V_M)/2)$ , and that  $V_{OST}$  includes  $V_{OS}$  plus the effects (on the input offset error,  $V_{OST}$ ) of temperature, CMRR, PSRR and  $A_{OL}$ .

### EQUATION 1-1:

$$G_{DM} = R_F/R_G$$

$$V_{CM} = (V_P + V_{DD}/2)/2$$

$$V_{OST} = V_{IN-} - V_{IN+}$$

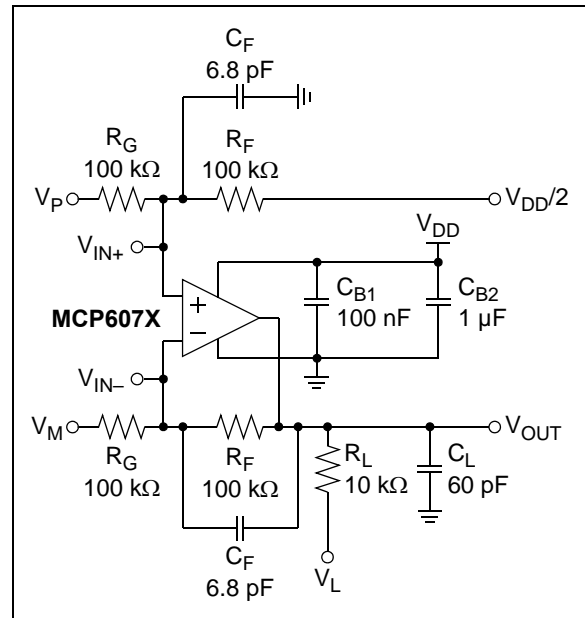
$$V_{OUT} = (V_{DD}/2) + (V_P - V_M) + V_{OST}(1 + G_{DM})$$

Where:

$$G_{DM} = \text{Differential Mode Gain} \quad (\text{V/V})$$

$$V_{CM} = \text{Op Amp's Common Mode Input Voltage} \quad (\text{V})$$

$$V_{OST} = \text{Op Amp's Total Input Offset Voltage} \quad (\text{mV})$$



**FIGURE 1-1:** AC and DC Test Circuit for Most Specifications.

# MCP6071/2/4

---

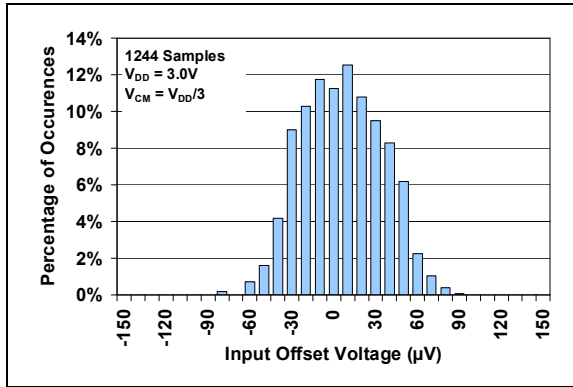
[查询MCP6074供应商](#)

**NOTES:**

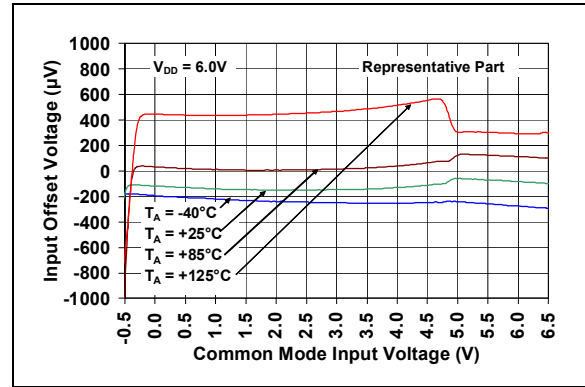
## 2.0 TYPICAL PERFORMANCE CURVES

**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

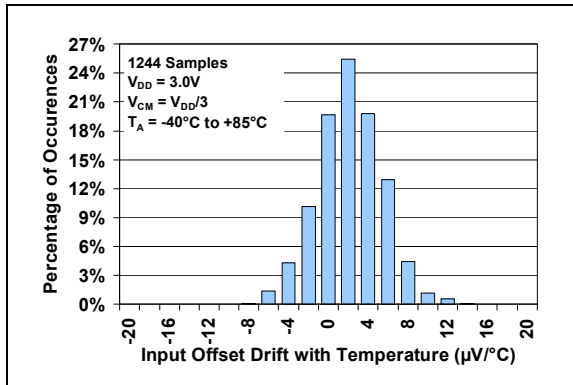
**Note:** Unless otherwise indicated,  $T_A = +25^\circ\text{C}$ ,  $V_{DD} = +1.8\text{V}$  to  $+6.0\text{V}$ ,  $V_{SS} = \text{GND}$ ,  $V_{CM} = V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $V_L = V_{DD}/2$ ,  $R_L = 10\text{ k}\Omega$  to  $V_L$  and  $C_L = 60\text{ pF}$ .



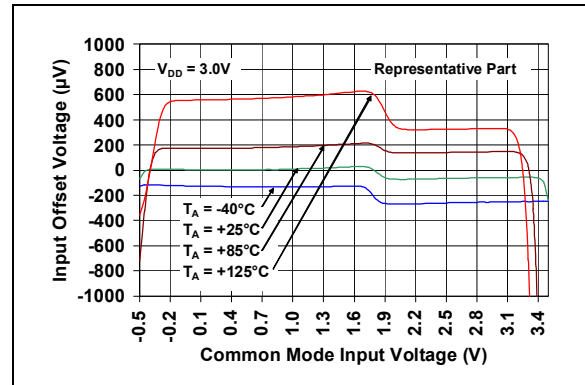
**FIGURE 2-1:** Input Offset Voltage with  $V_{DD} = 3.0\text{V}$ .



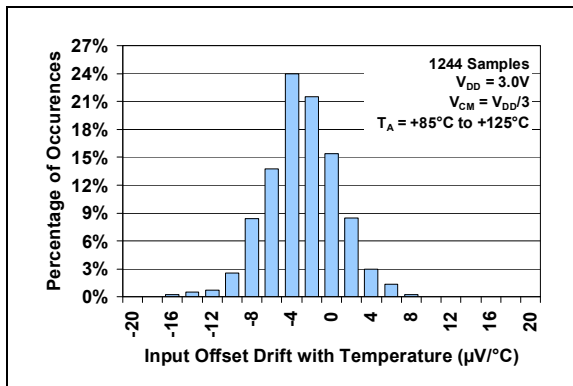
**FIGURE 2-4:** Input Offset Voltage vs. Common Mode Input Voltage with  $V_{DD} = 6.0\text{V}$ .



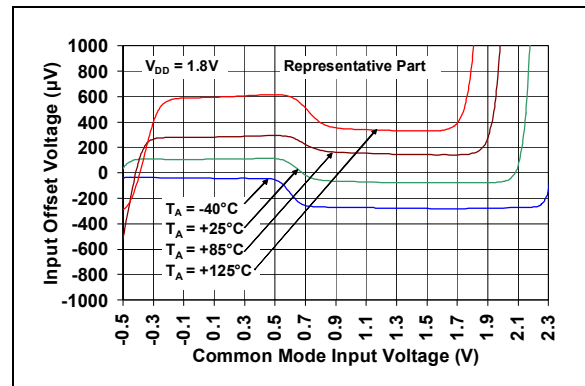
**FIGURE 2-2:** Input Offset Voltage Drift with  $V_{DD} = 3.0\text{V}$  and  $T_A \leq +85^\circ\text{C}$ .



**FIGURE 2-5:** Input Offset Voltage vs. Common Mode Input Voltage with  $V_{DD} = 3.0\text{V}$ .



**FIGURE 2-3:** Input Offset Voltage Drift with  $V_{DD} = 3.0\text{V}$  and  $T_A \geq +85^\circ\text{C}$ .

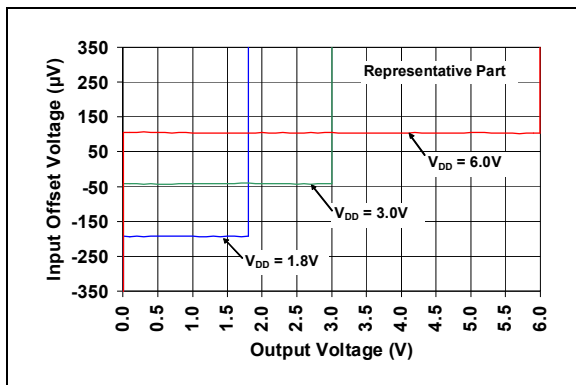


**FIGURE 2-6:** Input Offset Voltage vs. Common Mode Input Voltage with  $V_{DD} = 1.8\text{V}$ .

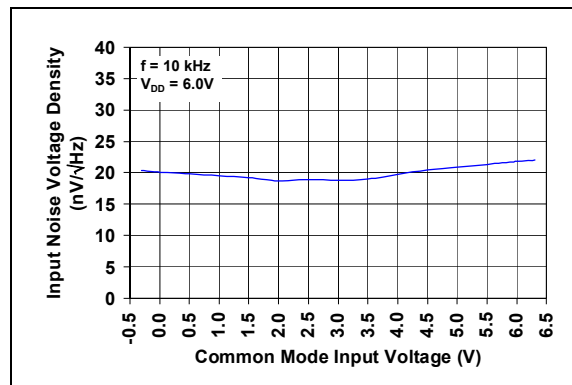
# MCP6071/2/4

[查询MCP6074供应商](#)

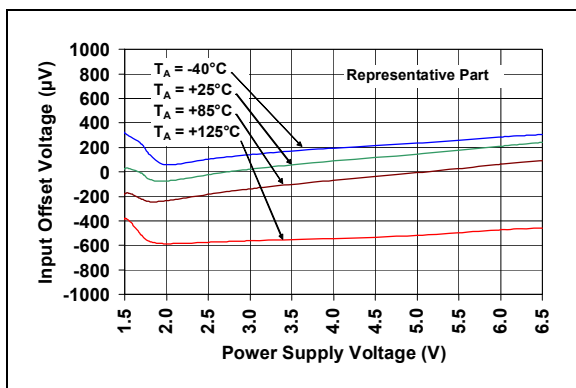
**Note:** Unless otherwise indicated,  $T_A = +25^\circ\text{C}$ ,  $V_{DD} = +1.8\text{V}$  to  $+6.0\text{V}$ ,  $V_{SS} = \text{GND}$ ,  $V_{CM} = V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $V_L = V_{DD}/2$ ,  $R_L = 10\text{ k}\Omega$  to  $V_L$  and  $C_L = 60\text{ pF}$ .



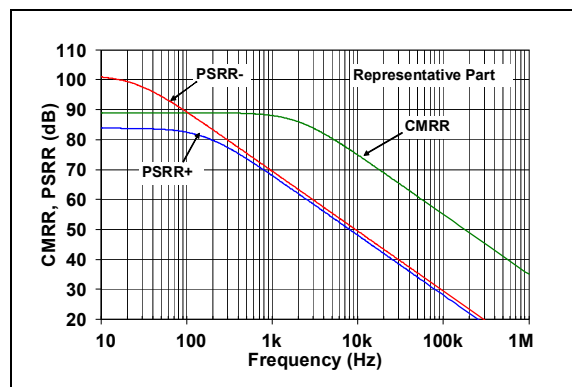
**FIGURE 2-7:** Input Offset Voltage vs. Output Voltage.



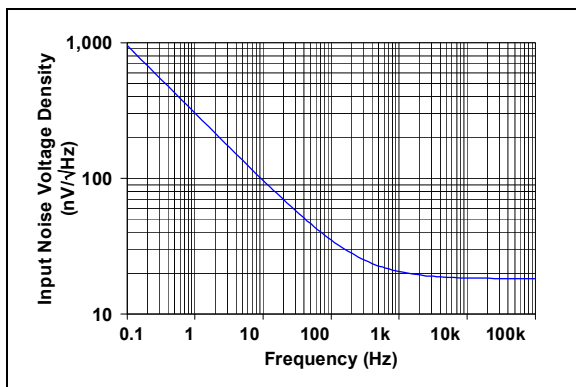
**FIGURE 2-10:** Input Noise Voltage Density vs. Common Mode Input Voltage.



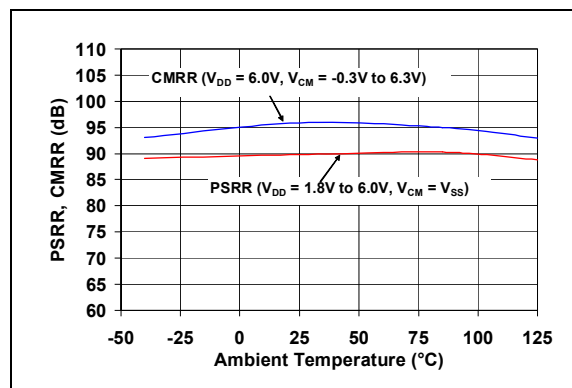
**FIGURE 2-8:** Input Offset Voltage vs. Power Supply Voltage.



**FIGURE 2-11:** CMRR, PSRR vs. Frequency.



**FIGURE 2-9:** Input Noise Voltage Density vs. Frequency.

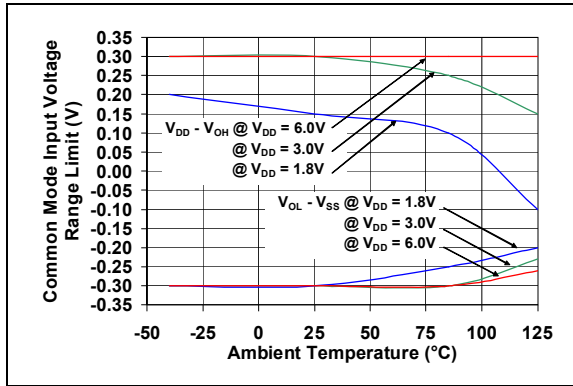


**FIGURE 2-12:** CMRR, PSRR vs. Ambient Temperature.

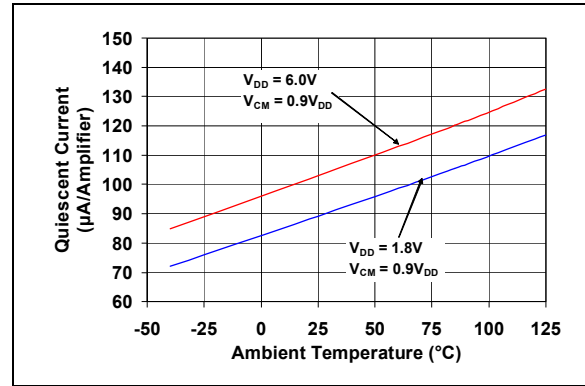


[查询MCP6074供应商](#)

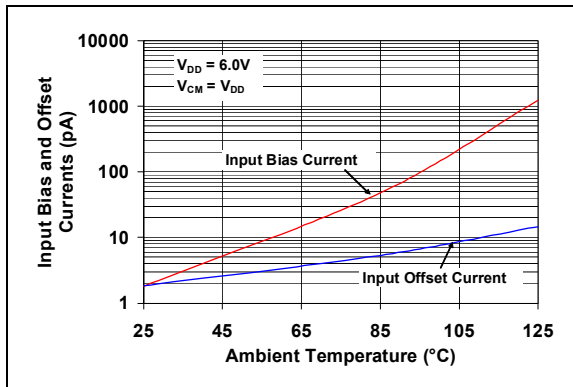
**Note:** Unless otherwise indicated,  $T_A = +25^\circ\text{C}$ ,  $V_{DD} = +1.8\text{V}$  to  $+6.0\text{V}$ ,  $V_{SS} = \text{GND}$ ,  $V_{CM} = V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $V_L = V_{DD}/2$ ,  $R_L = 10\text{ k}\Omega$  to  $V_L$  and  $C_L = 60\text{ pF}$ .



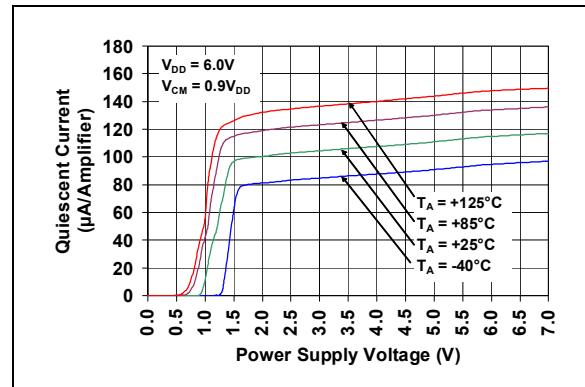
**FIGURE 2-13:** Common Mode Input Voltage Range Limit vs. Ambient Temperature.



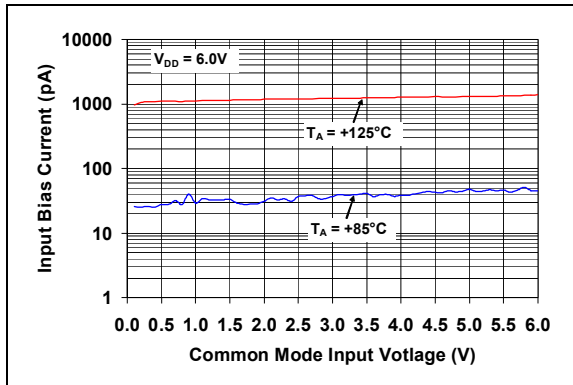
**FIGURE 2-16:** Quiescent Current vs. Ambient Temperature with  $V_{CM} = 0.9V_{DD}$ .



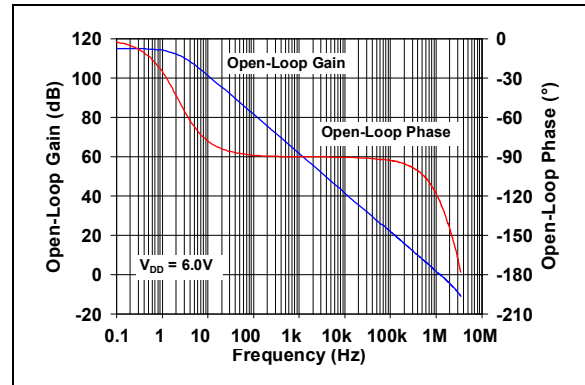
**FIGURE 2-14:** Input Bias, Offset Currents vs. Ambient Temperature.



**FIGURE 2-17:** Quiescent Current vs. Power Supply Voltage with  $V_{CM} = 0.9V_{DD}$ .



**FIGURE 2-15:** Input Bias Current vs. Common Mode Input Voltage.

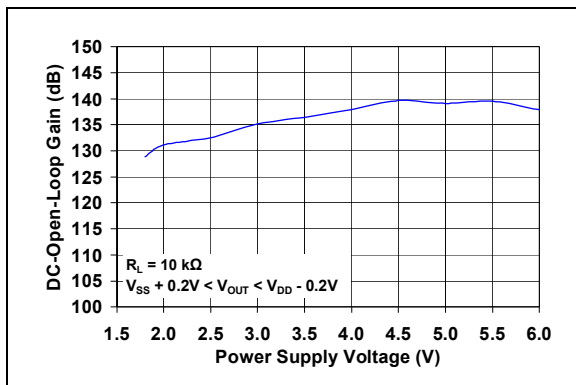


**FIGURE 2-18:** Open-Loop Gain, Phase vs. Frequency.

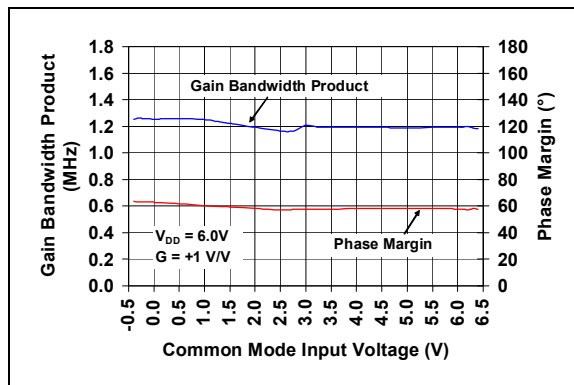
# MCP6071/2/4

[查询MCP6074供应商](#)

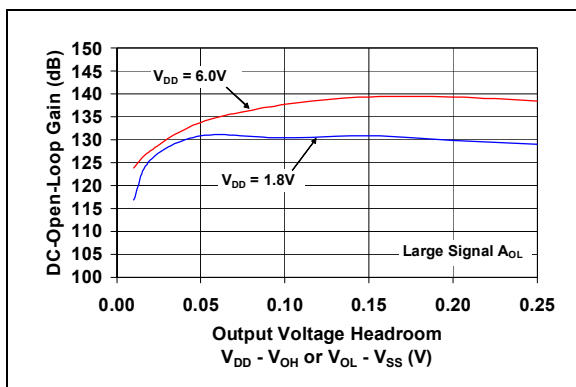
**Note:** Unless otherwise indicated,  $T_A = +25^\circ\text{C}$ ,  $V_{DD} = +1.8\text{V}$  to  $+6.0\text{V}$ ,  $V_{SS} = \text{GND}$ ,  $V_{CM} = V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $V_L = V_{DD}/2$ ,  $R_L = 10\text{ k}\Omega$  to  $V_L$  and  $C_L = 60\text{ pF}$ .



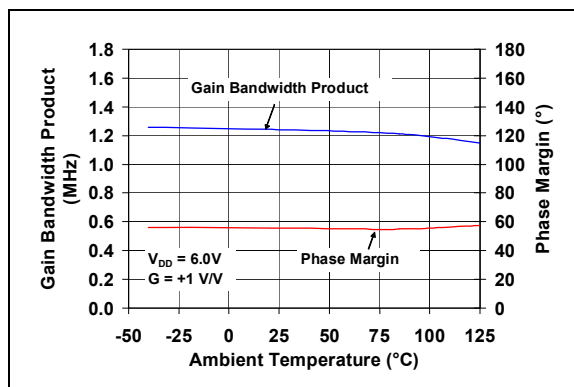
**FIGURE 2-19:** DC Open-Loop Gain vs. Power Supply Voltage.



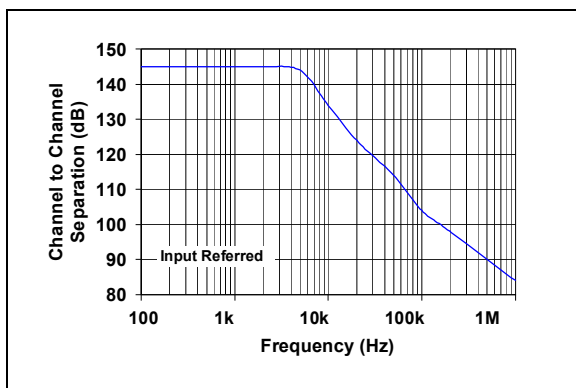
**FIGURE 2-22:** Gain Bandwidth Product, Phase Margin vs. Common Mode Input Voltage.



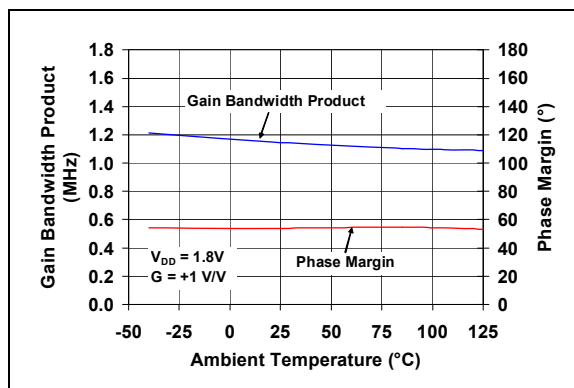
**FIGURE 2-20:** DC Open-Loop Gain vs. Output Voltage Headroom.



**FIGURE 2-23:** Gain Bandwidth Product, Phase Margin vs. Ambient Temperature.



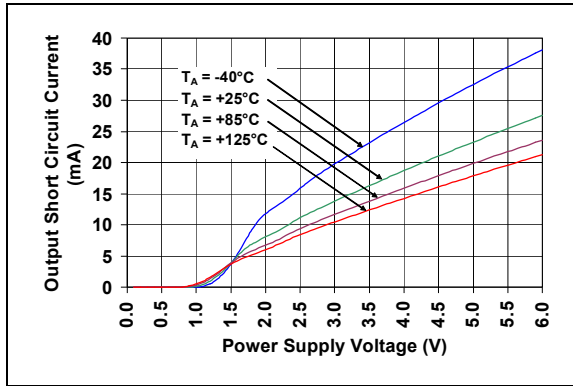
**FIGURE 2-21:** Channel-to-Channel Separation vs. Frequency (MCP6072/4 only).



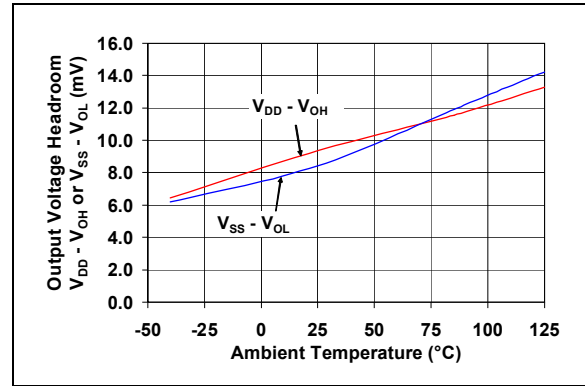
**FIGURE 2-24:** Gain Bandwidth Product, Phase Margin vs. Ambient Temperature.

## 查询MCP6074供应商

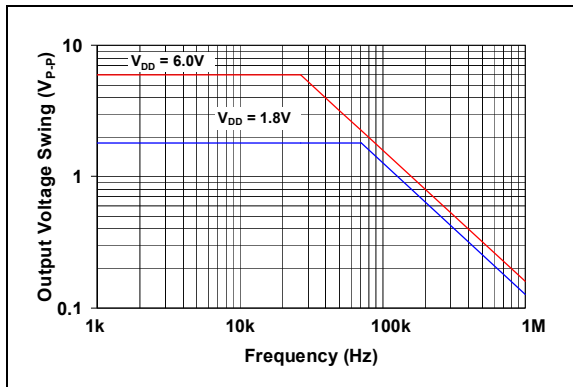
**Note:** Unless otherwise indicated,  $T_A = +25^\circ\text{C}$ ,  $V_{DD} = +1.8\text{V}$  to  $+6.0\text{V}$ ,  $V_{SS} = \text{GND}$ ,  $V_{CM} = V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $V_L = V_{DD}/2$ ,  $R_L = 10\text{ k}\Omega$  to  $V_L$  and  $C_L = 60\text{ pF}$ .



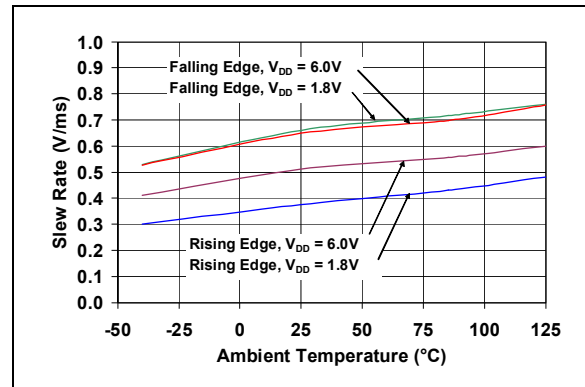
**FIGURE 2-25:** Output Short Circuit Current vs. Power Supply Voltage.



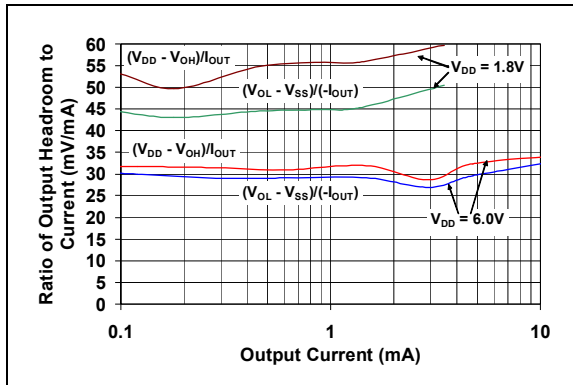
**FIGURE 2-28:** Output Voltage Headroom vs. Ambient Temperature.



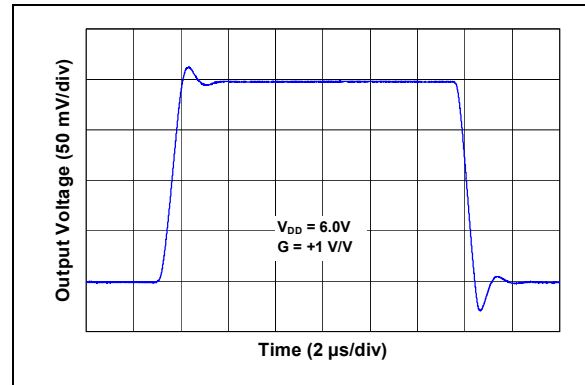
**FIGURE 2-26:** Output Voltage Swing vs. Frequency.



**FIGURE 2-29:** Slew Rate vs. Ambient Temperature.



**FIGURE 2-27:** Ratio of Output Voltage Headroom to Output Current vs. Output Current.

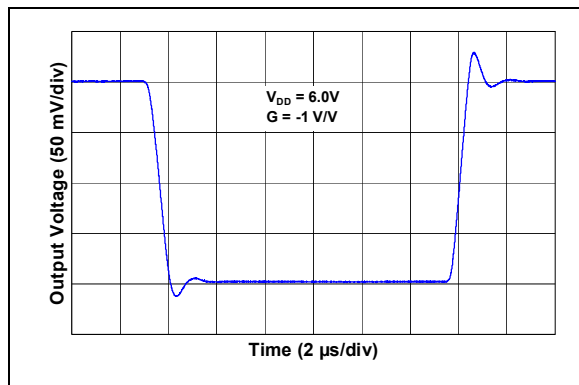


**FIGURE 2-30:** Small Signal Non-Inverting Pulse Response.

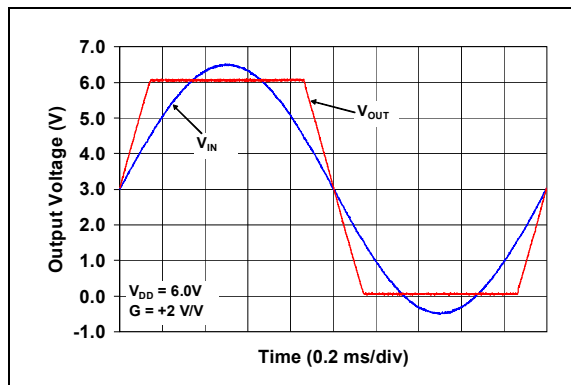
# MCP6071/2/4

[查询MCP6074供应商](#)

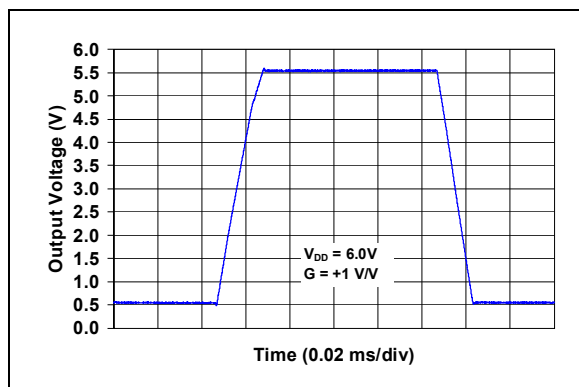
**Note:** Unless otherwise indicated,  $T_A = +25^\circ\text{C}$ ,  $V_{DD} = +1.8\text{V}$  to  $+6.0\text{V}$ ,  $V_{SS} = \text{GND}$ ,  $V_{CM} = V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $V_L = V_{DD}/2$ ,  $R_L = 10\text{ k}\Omega$  to  $V_L$  and  $C_L = 60\text{ pF}$ .



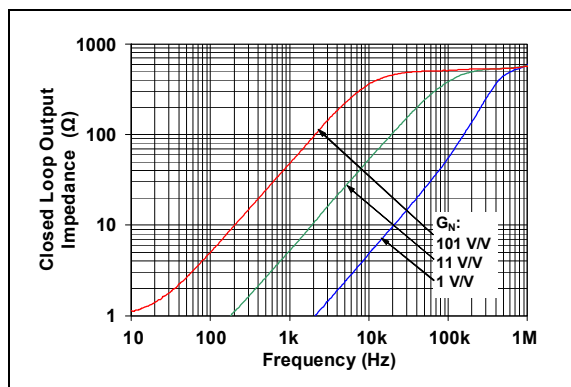
**FIGURE 2-31:** Small Signal Inverting Pulse Response.



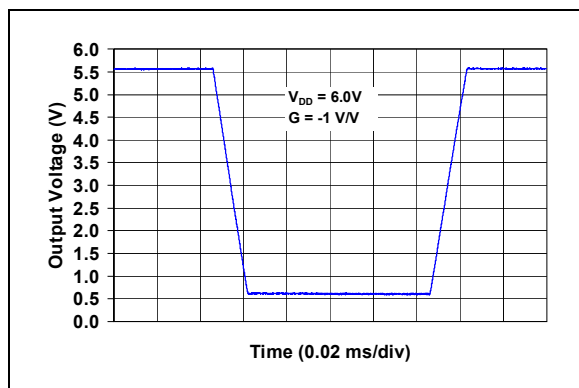
**FIGURE 2-34:** The MCP6071/2/4 Shows No Phase Reversal.



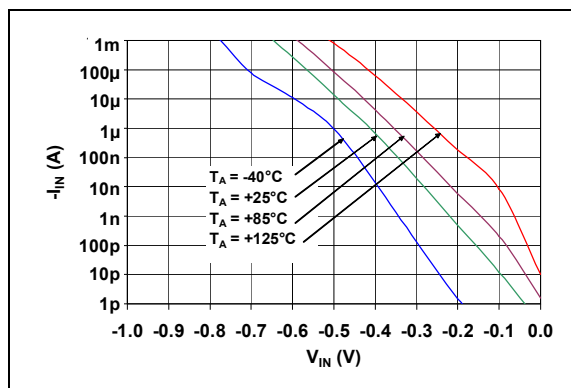
**FIGURE 2-32:** Large Signal Non-Inverting Pulse Response.



**FIGURE 2-35:** Closed Loop Output Impedance vs. Frequency.



**FIGURE 2-33:** Large Signal Inverting Pulse Response.



**FIGURE 2-36:** Measured Input Current vs. Input Voltage (below  $V_{SS}$ ).

### 3.0 PIN DESCRIPTIONS

Descriptions of the pins are listed in [Table 3-1](#).

**TABLE 3-1: PIN FUNCTION TABLE**

MCP6071		MCP6072		MCP6074	Symbol	Description
SOIC	2x3 TDFN	SOIC	2x3 TDFN	SOIC, TSSOP		
6	6	1	1	1	$V_{OUT}, V_{OUTA}$	Analog Output (op amp A)
2	2	2	2	2	$V_{IN-}, V_{INA-}$	Inverting Input (op amp A)
3	3	3	3	3	$V_{IN+}, V_{INA+}$	Non-inverting Input (op amp A)
7	7	8	8	4	$V_{DD}$	Positive Power Supply
—	—	5	5	5	$V_{INB+}$	Non-inverting Input (op amp B)
—	—	6	6	6	$V_{INB-}$	Inverting Input (op amp B)
—	—	7	7	7	$V_{OUTB}$	Analog Output (op amp B)
—	—	—	—	8	$V_{OUTC}$	Analog Output (op amp C)
—	—	—	—	9	$V_{INC-}$	Inverting Input (op amp C)
—	—	—	—	10	$V_{INC+}$	Non-inverting Input (op amp C)
4	4	4	4	11	$V_{SS}$	Negative Power Supply
—	—	—	—	12	$V_{IND+}$	Non-inverting Input (op amp D)
—	—	—	—	13	$V_{IND-}$	Inverting Input (op amp D)
—	—	—	—	14	$V_{OUTD}$	Analog Output (op amp D)
1, 5, 8	1, 5, 8	—	—	—	NC	No Internal Connection
—	9	—	9	—	EP	Exposed Thermal Pad (EP); must be connected to $V_{SS}$ .

#### 3.1 Analog Outputs

The output pins are low-impedance voltage sources.

#### 3.2 Analog Inputs

The non-inverting and inverting inputs are high-impedance CMOS inputs with low bias currents.

#### 3.3 Power Supply Pins

The positive power supply ( $V_{DD}$ ) is 1.8V to 6.0V higher than the negative power supply ( $V_{SS}$ ). For normal operation, the other pins are at voltages between  $V_{SS}$  and  $V_{DD}$ .

Typically, these parts are used in a single (positive) supply configuration. In this case,  $V_{SS}$  is connected to ground and  $V_{DD}$  is connected to the supply.  $V_{DD}$  will need bypass capacitors.

#### 3.4 Exposed Thermal Pad (EP)

There is an internal electrical connection between the Exposed Thermal Pad (EP) and the  $V_{SS}$  pin; they must be connected to the same potential on the Printed Circuit Board (PCB).

# MCP6071/2/4

---

[查询MCP6074供应商](#)

**NOTES:**

## 4.0 APPLICATION INFORMATION

The MCP6071/2/4 family of op amps is manufactured using Microchip's state-of-the-art CMOS process and is specifically designed for low-power, high precision applications.

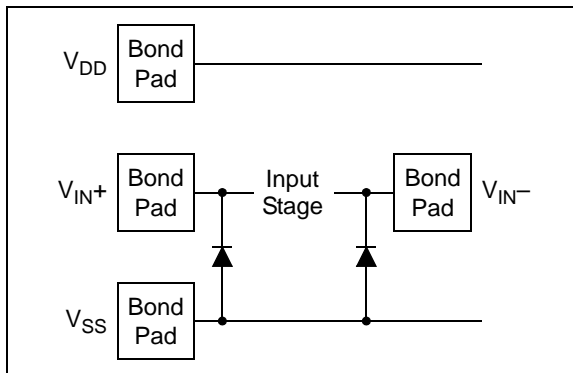
### 4.1 Rail-to-Rail Input

#### 4.1.1 PHASE REVERSAL

The MCP6071/2/4 op amps are designed to prevent phase reversal when the input pins exceed the supply voltages. Figure 2-34 shows the input voltage exceeding the supply voltage without any phase reversal.

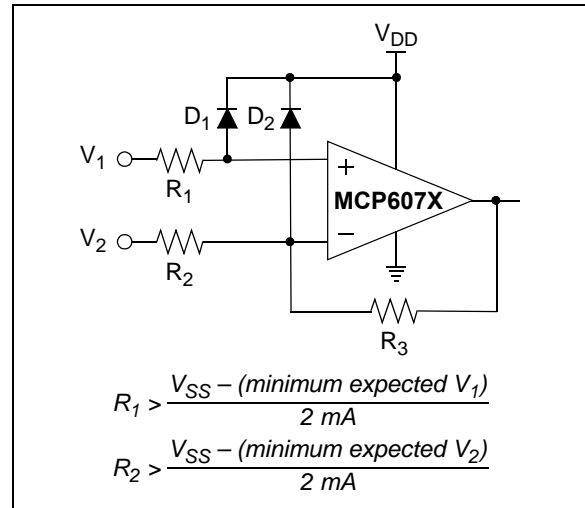
#### 4.1.2 INPUT VOLTAGE AND CURRENT LIMITS

The ESD protection on the inputs can be depicted as shown in Figure 4-1. This structure was chosen to protect the input transistors and to minimize input bias current ( $I_B$ ). The input ESD diodes clamp the inputs when they try to go more than one diode drop below  $V_{SS}$ . They also clamp any voltage that goes too far above  $V_{DD}$ ; their breakdown voltage is high enough to allow normal operation and low enough to bypass ESD events within the specified limits.



**FIGURE 4-1:** Simplified Analog Input ESD Structures.

In order to prevent damage and/or improper operation of these op amps, the circuit they are in must limit the voltages and currents at the  $V_{IN+}$  and  $V_{IN-}$  pins (see **Absolute Maximum Ratings** at the beginning of **Section 1.0 "Electrical Characteristics"**). Figure 4-2 shows the recommended approach to protecting these inputs. The internal ESD diodes prevent the input pins ( $V_{IN+}$  and  $V_{IN-}$ ) from going too far below ground, and the resistors  $R_1$  and  $R_2$  limit the possible current drawn out of the input pins. Diodes  $D_1$  and  $D_2$  prevent the input pins ( $V_{IN+}$  and  $V_{IN-}$ ) from going too far above  $V_{DD}$ . When implemented as shown, resistors  $R_1$  and  $R_2$  also limit the current through  $D_1$  and  $D_2$ .



**FIGURE 4-2:** Protecting the Analog Inputs.

It is also possible to connect the diodes to the left of the resistors  $R_1$  and  $R_2$ . In this case, the currents through the diodes  $D_1$  and  $D_2$  need to be limited by some other mechanism. The resistors then serve as in-rush current limiters; the DC currents into the input pins ( $V_{IN+}$  and  $V_{IN-}$ ) should be very small. A significant amount of current can flow out of the inputs when the common mode voltage ( $V_{CM}$ ) is below ground ( $V_{SS}$ ). (See Figure 2-36).

#### 4.1.3 NORMAL OPERATION

The input stage of the MCP6071/2/4 op amps uses two differential input stages in parallel. One operates at a low common mode input voltage ( $V_{CM}$ ), while the other operates at a high  $V_{CM}$ . With this topology, the device operates with a  $V_{CM}$  up to 300 mV above  $V_{DD}$  and 300 mV below  $V_{SS}$ . (See Figure 2-13). The input offset voltage is measured at  $V_{CM} = V_{SS} - 0.3V$  and  $V_{DD} + 0.3V$  to ensure proper operation.

The transition between the input stages occurs when  $V_{CM}$  is near  $V_{DD} - 1.1V$  (See Figures 2-4, 2-5 and Figure 2-6). For the best distortion performance and gain linearity, with non-inverting gains, avoid this region of operation.

## 4.2 Rail-to-Rail Output

The output voltage range of the MCP6071/2/4 op amps is  $V_{SS} + 15 \text{ mV}$  (minimum) and  $V_{DD} - 15 \text{ mV}$  (maximum) when  $R_L = 10 \text{ k}\Omega$  is connected to  $V_{DD}/2$  and  $V_{DD} = 6.0V$ . Refer to Figures 2-27 and 2-28 for more information.

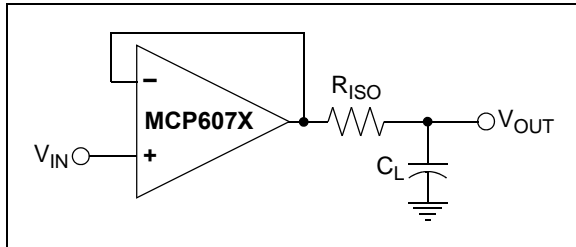
# MCP6071/2/4

[查询MCP6074供应商](#)

## 4.3 Capacitive Loads

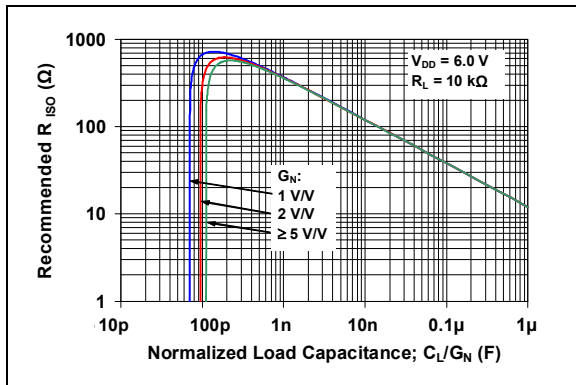
Driving large capacitive loads can cause stability problems for voltage feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases and the closed-loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response. While a unity-gain buffer ( $G = +1$ ) is the most sensitive to capacitive loads, all gains show the same general behavior.

When driving large capacitive loads with these op amps (e.g.,  $> 100$  pF when  $G = +1$ ), a small series resistor at the output ( $R_{ISO}$  in Figure 4-3) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. The bandwidth will be generally lower than the bandwidth with no capacitance load.



**FIGURE 4-3:** Output Resistor,  $R_{ISO}$  Stabilizes Large Capacitive Loads.

Figure 4-4 gives recommended  $R_{ISO}$  values for different capacitive loads and gains. The x-axis is the normalized load capacitance ( $C_L/G_N$ ), where  $G_N$  is the circuit's noise gain. For non-inverting gains,  $G_N$  and the Signal Gain are equal. For inverting gains,  $G_N$  is  $1 + |\text{Signal Gain}|$  (e.g.,  $-1$  V/V gives  $G_N = +2$  V/V).



**FIGURE 4-4:** Recommended  $R_{ISO}$  Values for Capacitive Loads.

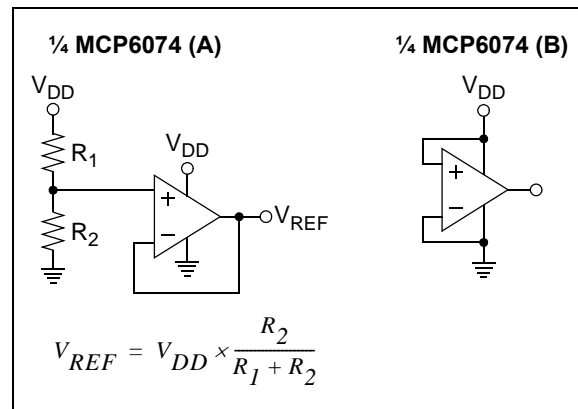
After selecting  $R_{ISO}$  for your circuit, double-check the resulting frequency response peaking and step response overshoot. Modify  $R_{ISO}$ 's value until the response is reasonable. Bench evaluation and simulations with the MCP6071/2/4 SPICE macro model are very helpful.

## 4.4 Supply Bypass

With this family of operational amplifiers, the power supply pin ( $V_{DD}$  for single-supply) should have a local bypass capacitor (i.e.,  $0.01$   $\mu$ F to  $0.1$   $\mu$ F) within 2 mm for good high frequency performance. It can use a bulk capacitor (i.e.,  $1$   $\mu$ F or larger) within 100 mm to provide large, slow currents. This bulk capacitor can be shared with other analog parts.

## 4.5 Unused Op Amps

An unused op amp in a quad package (MCP6074) should be configured as shown in Figure 4-5. These circuits prevent the output from toggling and causing crosstalk. Circuit A sets the op amp at its minimum noise gain. The resistor divider produces any desired reference voltage within the output voltage range of the op amp; the op amp buffers that reference voltage. Circuit B uses the minimum number of components and operates as a comparator, but it may draw more current.



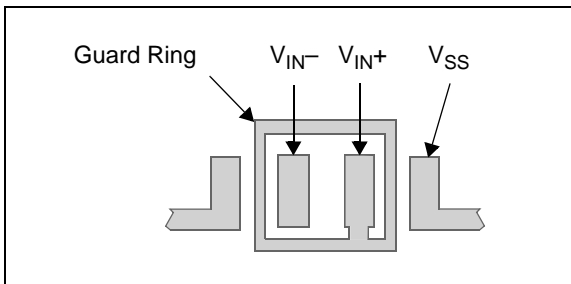
**FIGURE 4-5:** Unused Op Amps.



#### 4.6 PCB Surface Leakage

In applications where low input bias current is critical, Printed Circuit Board (PCB) surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low humidity conditions, a typical resistance between nearby traces is  $10^{12}\Omega$ . A 5V difference would cause 5 pA of current to flow; which is greater than the MCP6071/2/4 family's bias current at +25°C ( $\pm 1.0$  pA, typical).

The easiest way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. An example of this type of layout is shown in Figure 4-6.



**FIGURE 4-6:** Example Guard Ring Layout for Inverting Gain.

1. Non-inverting Gain and Unity-Gain Buffer:
  - a. Connect the non-inverting pin ( $V_{IN+}$ ) to the input with a wire that does not touch the PCB surface.
  - b. Connect the guard ring to the inverting input pin ( $V_{IN-}$ ). This biases the guard ring to the common mode input voltage.
2. Inverting Gain and Transimpedance Gain Amplifiers (convert current to voltage, such as photo detectors):
  - a. Connect the guard ring to the non-inverting input pin ( $V_{IN+}$ ). This biases the guard ring to the same reference voltage as the op amp (e.g.,  $V_{DD}/2$  or ground).
  - b. Connect the inverting pin ( $V_{IN-}$ ) to the input with a wire that does not touch the PCB surface.

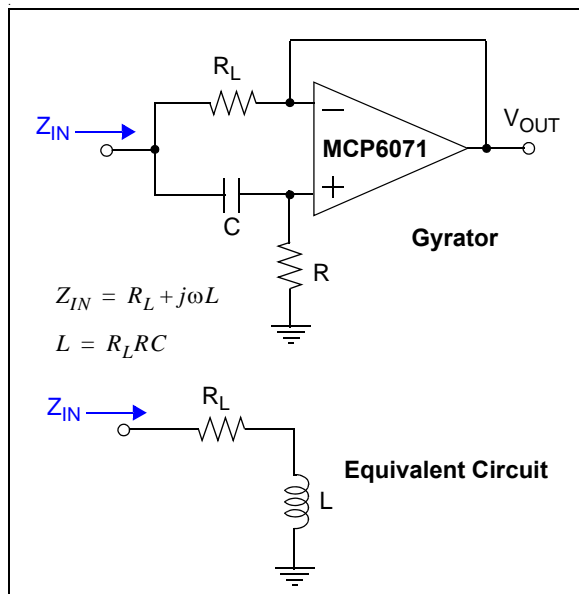
# MCP6071/2/4

[查询MCP6074供应商](#)

## 4.7 Application Circuits

### 4.7.1 GYRATOR

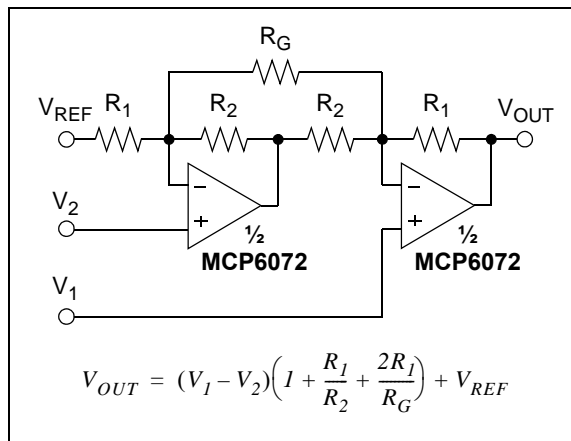
The MCP6071/2/4 op amps can be used in gyrator applications. The gyrator is an electric circuit which can make a capacitive circuit behave inductively. [Figure 4-7](#) shows an example of a gyrator simulating inductance, with an approximately equivalent circuit below. The two  $Z_{IN}$  have similar values in typical applications. The primary application for a gyrator is to reduce the size and cost of a system by removing the need for bulky, heavy and expensive inductors. For example, RLC bandpass filter characteristics can be realized with capacitors, resistors and operational amplifiers without using inductors. Moreover, gyrators will typically have higher accuracy than real inductors, due to the lower cost of precision capacitors than inductors.



**FIGURE 4-7:** Gyrator.

### 4.7.2 INSTRUMENTATION AMPLIFIER

The MCP6071/2/4 op amps are well suited for conditioning sensor signals in battery-powered applications. [Figure 4-8](#) shows a two op amp instrumentation amplifier, using the MCP6072, that works well for applications requiring rejection of common mode noise at higher gains. The reference voltage ( $V_{REF}$ ) is supplied by a low impedance source. In single supply applications,  $V_{REF}$  is typically  $V_{DD}/2$ .

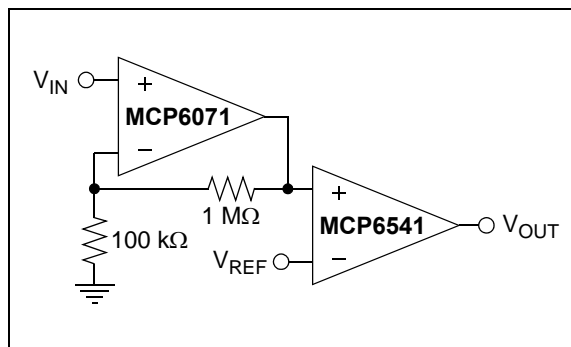


**FIGURE 4-8:** Two Op Amp Instrumentation Amplifier.

To obtain the best CMRR possible, and not limit the performance by the resistor tolerances, set a high gain with the  $R_G$  resistor.

### 4.7.3 PRECISION COMPARATOR

Use high gain before a comparator to improve the latter's input offset performance. [Figure 4-9](#) shows a gain of 11 V/V placed before a comparator. The reference voltage  $V_{REF}$  can be any value between the supply rails.



**FIGURE 4-9:** Precision, Non-inverting Comparator.

## 5.0 DESIGN AIDS

Microchip provides the basic design tools needed for the MCP6071/2/4 family of op amps.

### 5.1 SPICE Macro Model

The latest SPICE macro model for the MCP6071/2/4 op amps is available on the Microchip web site at [www.microchip.com](http://www.microchip.com). This model is intended to be an initial design tool that works well in the op amp's linear region of operation over the temperature range. See the model file for information on its capabilities.

Bench testing is a very important part of any design and cannot be replaced with simulations. Also, simulation results using this macro model need to be validated by comparing them to the data sheet specifications and characteristic curves.

### 5.2 FilterLab® Software

Microchip's FilterLab® software is an innovative software tool that simplifies analog active filter (using op amps) design. Available at no cost from the Microchip web site at [www.microchip.com/filterlab](http://www.microchip.com/filterlab), the FilterLab design tool provides full schematic diagrams of the filter circuit with component values. It also outputs the filter circuit in SPICE format, which can be used with the macro model to simulate actual filter performance.

### 5.3 Mindi™ Circuit Designer & Simulator

Microchip's Mindi™ Circuit Designer & Simulator aids in the design of various circuits useful for active filter, amplifier and power-management applications. It is a free online circuit designer & simulator available from the Microchip web site at [www.microchip.com/mindi](http://www.microchip.com/mindi). This interactive circuit designer & simulator enables designers to quickly generate circuit diagrams, simulate circuits. Circuits developed using the Mindi Circuit Designer & Simulator can be downloaded to a personal computer or workstation.

### 5.4 MAPS (Microchip Advanced Part Selector)

MAPS is a software tool that helps semiconductor professionals efficiently identify Microchip devices that fit a particular design requirement. Available at no cost from the Microchip website at [www.microchip.com/maps](http://www.microchip.com/maps), the MAPS is an overall selection tool for Microchip's product portfolio that includes Analog, Memory, MCUs and DSCs. Using this tool you can define a filter to sort features for a parametric search of devices and export side-by-side technical comparison reports. Helpful links are also provided for Datasheets, Purchase, and Sampling of Microchip parts.

## 5.5 Analog Demonstration and Evaluation Boards

Microchip offers a broad spectrum of Analog Demonstration and Evaluation Boards that are designed to help you achieve faster time to market. For a complete listing of these boards and their corresponding user's guides and technical information, visit the Microchip web site at [www.microchip.com/analogtools](http://www.microchip.com/analogtools).

Some boards that are especially useful are:

- MCP6XXX Amplifier Evaluation Board 1
- MCP6XXX Amplifier Evaluation Board 2
- MCP6XXX Amplifier Evaluation Board 3
- MCP6XXX Amplifier Evaluation Board 4
- Active Filter Demo Board Kit
- 5/6-Pin SOT-23 Evaluation Board, P/N VSUPEV2
- 8-Pin SOIC/MSOP/TSSOP/DIP Evaluation Board, P/N SOIC8EV
- 14-Pin SOIC/TSSOP/DIP Evaluation Board, P/N SOIC14EV

## 5.6 Application Notes

The following Microchip Analog Design Note and Application Notes are available on the Microchip web site at [www.microchip.com/appnotes](http://www.microchip.com/appnotes) and are recommended as supplemental reference resources.

- **ADN003:** "Select the Right Operational Amplifier for your Filtering Circuits", DS21821
- **AN722:** "Operational Amplifier Topologies and DC Specifications", DS00722
- **AN723:** "Operational Amplifier AC Specifications and Applications", DS00723
- **AN884:** "Driving Capacitive Loads With Op Amps", DS00884
- **AN990:** "Analog Sensor Conditioning Circuits – An Overview", DS00990
- **AN1177:** "Op Amp Precision Design: DC Errors", DS01177
- **AN1228:** "Op Amp Precision Design: Random Noise", DS01228

These application notes and others are listed in the design guide:

- "Signal Chain Design Guide", DS21825

# MCP6071/2/4

---

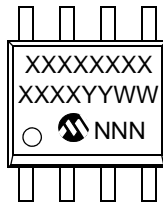
[查询MCP6074供应商](#)

**NOTES:**

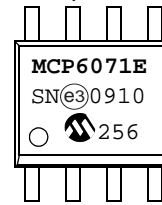
## 6.0 PACKAGING INFORMATION

### 6.1 Package Marking Information

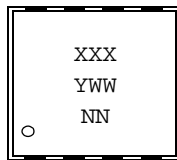
8-Lead SOIC (150 mil) (MCP6071, MCP6072)



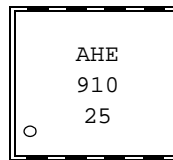
Example:



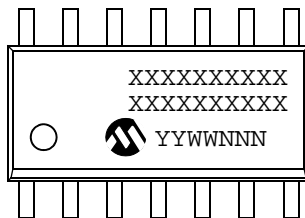
8-Lead 2x3 TDFN (MCP6071, MCP6072)



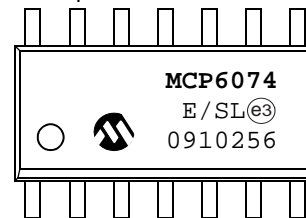
Example:



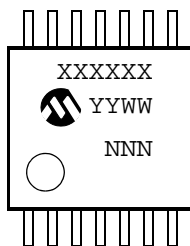
14-Lead SOIC (150 mil) (MCP6074)



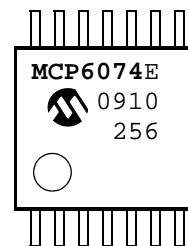
Example:



14-Lead TSSOP (MCP6074)



Example:



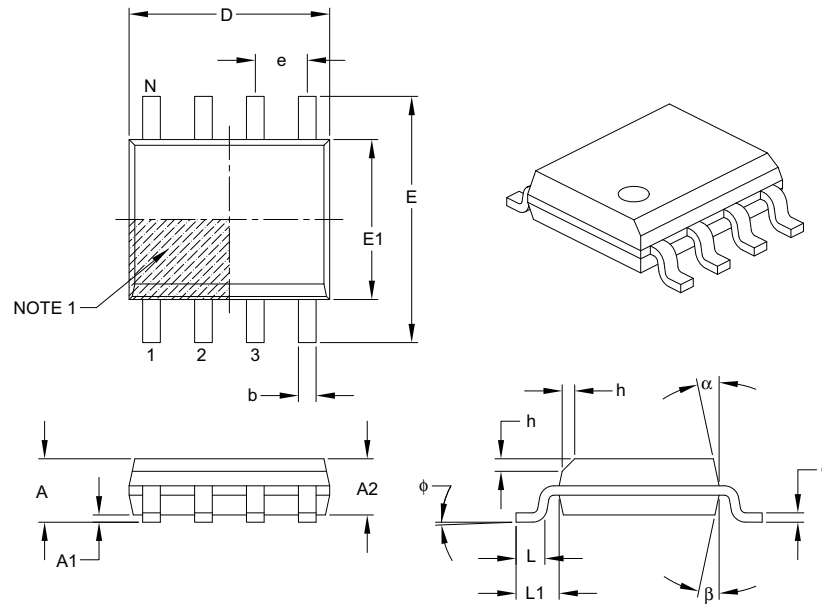
<b>Legend:</b>	XX...X	Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.

**Note:** In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

[查询MCP6074供应商](#)

### 8-Lead Plastic Small Outline (SN) – Narrow, 3.90 mm Body [SOIC]

**Note:**

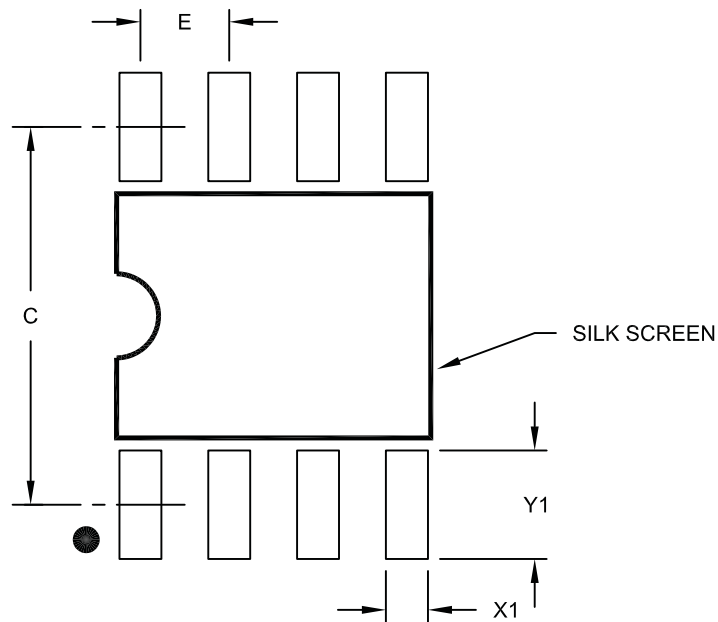


	$\phi$		
	$\alpha$		
	$\beta$		

**Notes:**

## 8-Lead Plastic Small Outline (SN) – Narrow, 3.90 mm Body [SOIC]

**Note:**



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	1.27 BSC		
Contact Pad Spacing	C		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

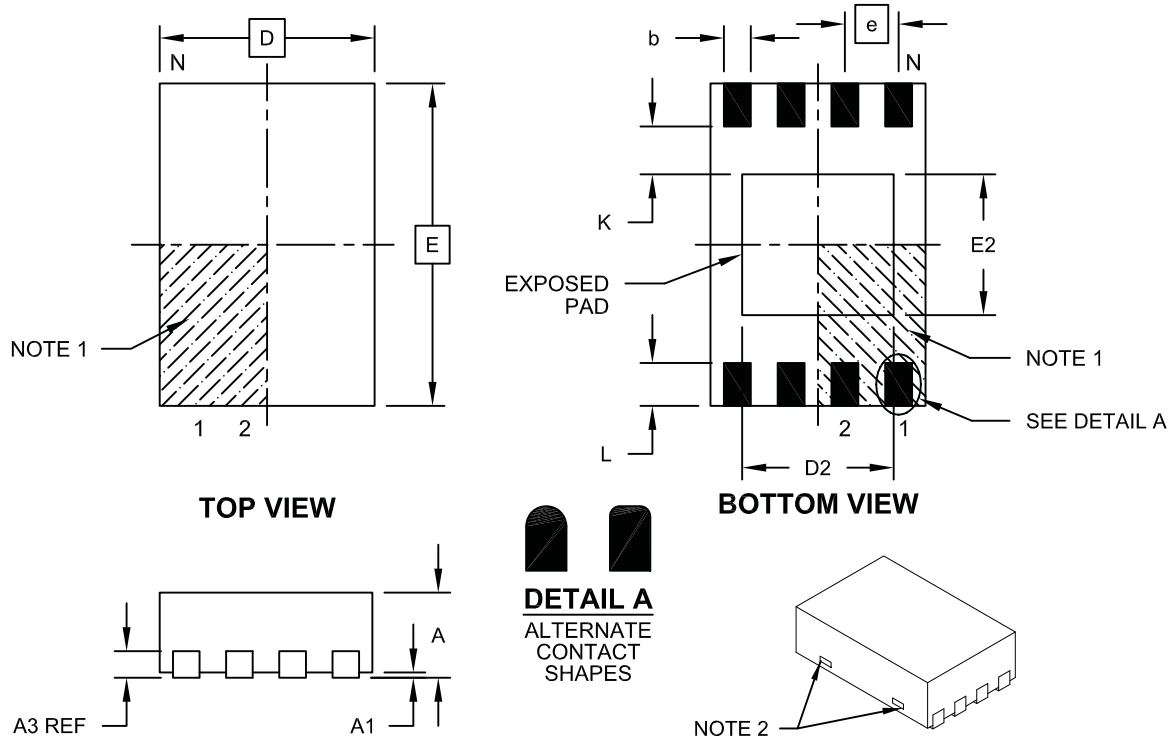
Microchip Technology Drawing No. C04-2057A

# MCP6071/2/4

[查询MCP6074供应商](#)

## 8-Lead Plastic Dual Flat, No Lead Package (MN) – 2x3x0.75 mm Body [TDFN]

**Note:**



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N	8		
Pitch	e	0.50 BSC		
Overall Height	A	0.70	0.75	0.80
Standoff	A1	0.00	0.02	0.05
Contact Thickness	A3	0.20 REF		
Overall Length	D	2.00 BSC		
Overall Width	E	3.00 BSC		
Exposed Pad Length	D2	1.20	-	1.60
Exposed Pad Width	E2	1.20	-	1.60
Contact Width	b	0.20	0.25	0.30
Contact Length	L	0.25	0.30	0.45
Contact-to-Exposed Pad	K	0.20	-	-

### Notes:

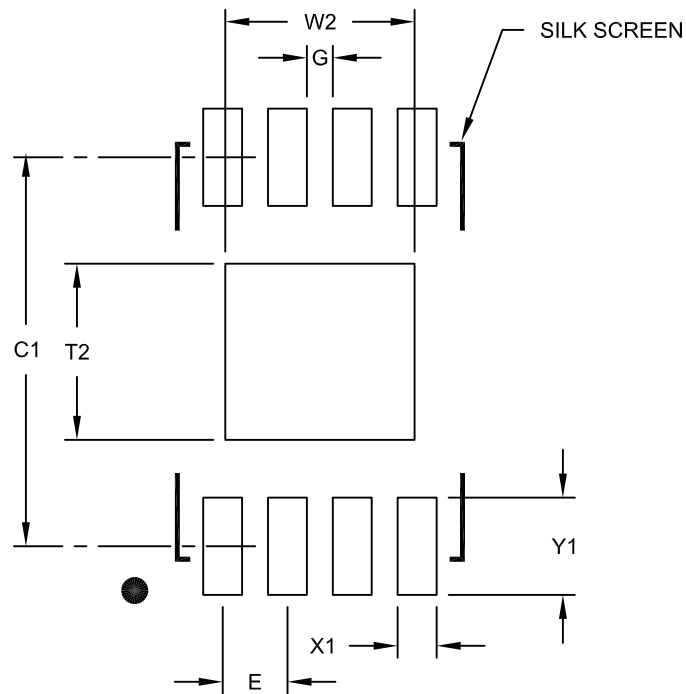
1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Package may have one or more exposed tie bars at ends.
3. Package is saw singulated
4. Dimensioning and tolerancing per ASME Y14.5M
  - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
  - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-129B



## 8-Lead Plastic Dual Flat, No Lead Package (MN) – 2x3x0.75 mm Body [TDFN]

**Note:**



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	0.50 BSC		
Optional Center Pad Width	W2			1.46
Optional Center Pad Length	T2			1.36
Contact Pad Spacing	C1		3.00	
Contact Pad Width (X8)	X1			0.30
Contact Pad Length (X8)	Y1			0.75
Distance Between Pads	G	0.20		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

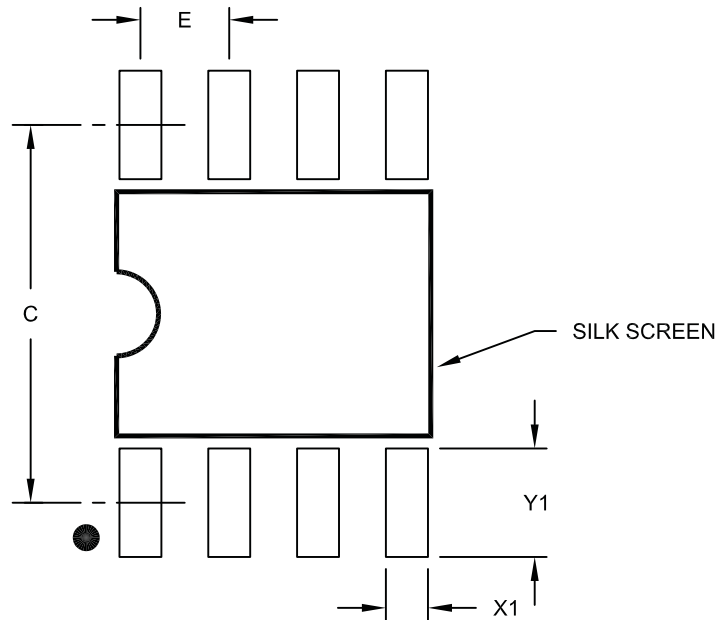
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2129A



## 8-Lead Plastic Small Outline (SN) – Narrow, 3.90 mm Body [SOIC]

**Note:**



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	1.27 BSC		
Contact Pad Spacing	C		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

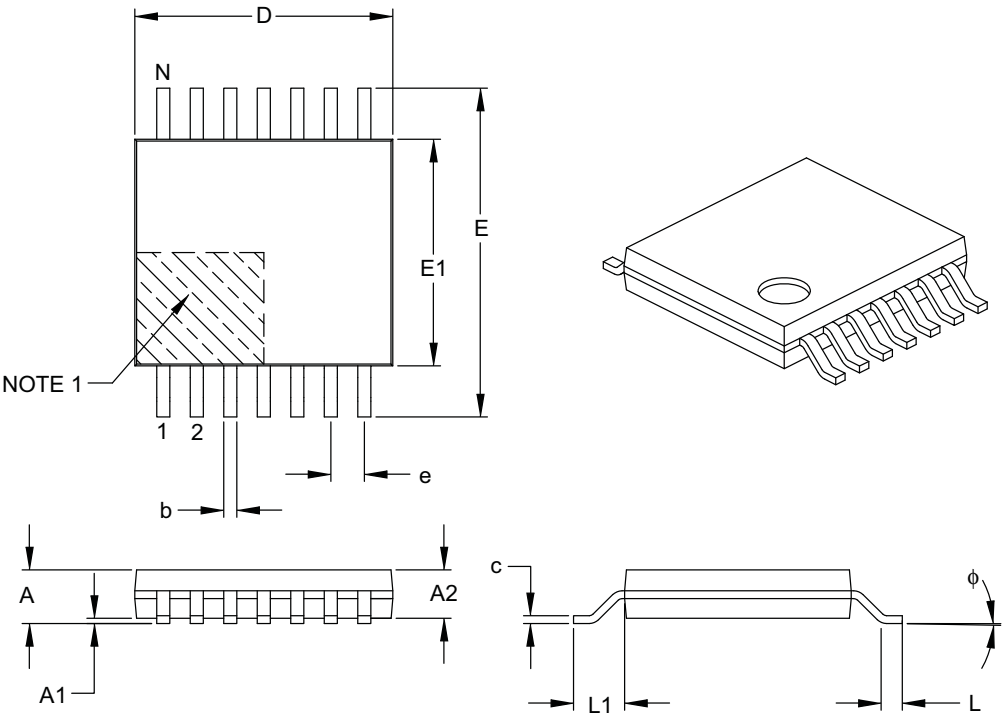
Microchip Technology Drawing No. C04-2057A

# MCP6071/2/4

[查询MCP6074供应商](#)

## 14-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm Body [TSSOP]

**Note:**



	$\phi$			

**Notes:**

[查询MCP6074供应商](#)

## **APPENDIX A: REVISION HISTORY**

### **Revision A (March 2009)**

- Original Release of this Document.

# MCP6071/2/4

---

[查询MCP6074供应商](#)

**NOTES:**

## PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>PART NO.</u>	<u>X</u>	<u>/XX</u>	<b>Examples:</b>
Device	Temperature Range	Package	
Device:	MCP6071: MCP6071T:	Single Op Amp Single Op Amp (Tape and Reel) (SOIC and 2x3 TDFN)	a) MCP6071-E/SN: 8LD SOIC pkg b) MCP6071T-E/SN: Tape and Reel, 8LD SOIC pkg
	MCP6072: MCP6072T:	Dual Op Amp Dual Op Amp (Tape and Reel) (SOIC and 2x3 TDFN)	c) MCP6071-E/MNY: 8LD 2x3 TDFN pkg d) MCP6071T-E/MNY: Tape and Reel, 8LD 2x3 TDFN pkg
	MCP6074: MCP6074T:	Quad Op Amp Quad Op Amp (Tape and Reel) (SOIC and TSSOP)	a) MCP6072-E/SN: 8LD SOIC pkg b) MCP6072T-E/SN: Tape and Reel, 8LD SOIC pkg c) MCP6072-E/MN: 8LD 2x3 TDFN pkg d) MCP6072T-E/MN: Tape and Reel, 8LD 2x3 TDFN pkg
Temperature Range:	E	= -40°C to +125°C	
Package:	MNY *	= Plastic Dual Flat, No Lead, (2x3 TDFN ) 8-leadd	a) MCP6074-E/SL: 14LD SOIC pkg b) MCP6074T-E/SL: Tape and Reel, 14LD SOIC pkg
	SL	= Plastic SOIC (150 mil Body), 14-lead	
	SN	= Plastic SOIC, (150 mil Body), 8-lead	c) MCP6074-E/ST: 14LD TSSOP pkg d) MCP6074T-E/ST: Tape and Reel, 14LD TSSOP pkg
	ST	= Plastic TSSOP (4.4mm Body), 14-lead	
	* Y = Nickel palladium gold manufacturing designator. Only available on the TDFN package.		

# MCP6071/2/4

---

[查询MCP6074供应商](#)

**NOTES:**



**Note the following details of the code protection feature on Microchip devices:**

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

---

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

**Trademarks**

The Microchip name and logo, the Microchip logo, Accuron, dsPIC, KEELoQ, KEELoQ logo, MPLAB, PIC, PICmicro, PICSTART, rfPIC, SmartShunt and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.


FilterLab, Linear Active Thermistor, MXDEV, MXLAB, SEEVAL, SmartSensor and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Analog-for-the-Digital Age, Application Maestro, CodeGuard, dsPICDEM, dsPICDEM.net, dsPICworks, dsSPEAK, ECAN, ECONOMONITOR, FanSense, In-Circuit Serial Programming, ICSP, ICEPIC, Mindi, MiWi, MPASM, MPLAB Certified logo, MPLIB, MPLINK, mTouch, nanoWatt XLP, PICkit, PICDEM, PICDEM.net, PICtail, PIC<sup>32</sup> logo, PowerCal, PowerInfo, PowerMate, PowerTool, REAL ICE, rfLAB, Select Mode, Total Endurance, TSHARC, WiperLock and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

All other trademarks mentioned herein are property of their respective companies.

© 2009, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

 Printed on recycled paper.

**QUALITY MANAGEMENT SYSTEM**  
**CERTIFIED BY DNV**  
**== ISO/TS 16949:2002 ==**

*Microchip received ISO/TS-16949:2002 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELoQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.*

## Worldwide Sales and Service

### AMERICAS

#### Corporate Office

2355 West Chandler Blvd.  
Chandler, AZ 85224-6199  
Tel: 480-792-7200  
Fax: 480-792-7277  
Technical Support:  
<http://support.microchip.com>  
Web Address:  
[www.microchip.com](http://www.microchip.com)

#### Atlanta

Duluth, GA  
Tel: 678-957-9614  
Fax: 678-957-1455

#### Boston

Westborough, MA  
Tel: 774-760-0087  
Fax: 774-760-0088

#### Chicago

Itasca, IL  
Tel: 630-285-0071  
Fax: 630-285-0075

#### Cleveland

Independence, OH  
Tel: 216-447-0464  
Fax: 216-447-0643

#### Dallas

Addison, TX  
Tel: 972-818-7423  
Fax: 972-818-2924

#### Detroit

Farmington Hills, MI  
Tel: 248-538-2250  
Fax: 248-538-2260

#### Kokomo

Kokomo, IN  
Tel: 765-864-8360  
Fax: 765-864-8387

#### Los Angeles

Mission Viejo, CA  
Tel: 949-462-9523  
Fax: 949-462-9608

#### Santa Clara

Santa Clara, CA  
Tel: 408-961-6444  
Fax: 408-961-6445

#### Toronto

Mississauga, Ontario,  
Canada  
Tel: 905-673-0699  
Fax: 905-673-6509

### ASIA/PACIFIC

#### Asia Pacific Office

Suites 3707-14, 37th Floor  
Tower 6, The Gateway  
Harbour City, Kowloon  
Hong Kong  
Tel: 852-2401-1200  
Fax: 852-2401-3431

#### Australia - Sydney

Tel: 61-2-9868-6733  
Fax: 61-2-9868-6755

#### China - Beijing

Tel: 86-10-8528-2100  
Fax: 86-10-8528-2104

#### China - Chengdu

Tel: 86-28-8665-5511  
Fax: 86-28-8665-7889

#### China - Hong Kong SAR

Tel: 852-2401-1200  
Fax: 852-2401-3431

#### China - Nanjing

Tel: 86-25-8473-2460  
Fax: 86-25-8473-2470

#### China - Qingdao

Tel: 86-532-8502-7355  
Fax: 86-532-8502-7205

#### China - Shanghai

Tel: 86-21-5407-5533  
Fax: 86-21-5407-5066

#### China - Shenyang

Tel: 86-24-2334-2829  
Fax: 86-24-2334-2393

#### China - Shenzhen

Tel: 86-755-8203-2660  
Fax: 86-755-8203-1760

#### China - Wuhan

Tel: 86-27-5980-5300  
Fax: 86-27-5980-5118

#### China - Xiamen

Tel: 86-592-2388138  
Fax: 86-592-2388130

#### China - Xian

Tel: 86-29-8833-7252  
Fax: 86-29-8833-7256

#### China - Zhuhai

Tel: 86-756-3210040  
Fax: 86-756-3210049

### ASIA/PACIFIC

#### India - Bangalore

Tel: 91-80-3090-4444  
Fax: 91-80-3090-4080

#### India - New Delhi

Tel: 91-11-4160-8631  
Fax: 91-11-4160-8632

#### India - Pune

Tel: 91-20-2566-1512  
Fax: 91-20-2566-1513

#### Japan - Yokohama

Tel: 81-45-471- 6166  
Fax: 81-45-471-6122

#### Korea - Daegu

Tel: 82-53-744-4301  
Fax: 82-53-744-4302

#### Korea - Seoul

Tel: 82-2-554-7200  
Fax: 82-2-558-5932 or  
82-2-558-5934

#### Malaysia - Kuala Lumpur

Tel: 60-3-6201-9857  
Fax: 60-3-6201-9859

#### Malaysia - Penang

Tel: 60-4-227-8870  
Fax: 60-4-227-4068

#### Philippines - Manila

Tel: 63-2-634-9065  
Fax: 63-2-634-9069

#### Singapore

Tel: 65-6334-8870  
Fax: 65-6334-8850

#### Taiwan - Hsin Chu

Tel: 886-3-572-9526  
Fax: 886-3-572-6459

#### Taiwan - Kaohsiung

Tel: 886-7-536-4818  
Fax: 886-7-536-4803

#### Taiwan - Taipei

Tel: 886-2-2500-6610  
Fax: 886-2-2508-0102

#### Thailand - Bangkok

Tel: 66-2-694-1351  
Fax: 66-2-694-1350

### EUROPE

#### Austria - Wels

Tel: 43-7242-2244-39  
Fax: 43-7242-2244-393

#### Denmark - Copenhagen

Tel: 45-4450-2828  
Fax: 45-4485-2829

#### France - Paris

Tel: 33-1-69-53-63-20  
Fax: 33-1-69-30-90-79

#### Germany - Munich

Tel: 49-89-627-144-0  
Fax: 49-89-627-144-44

#### Italy - Milan

Tel: 39-0331-742611  
Fax: 39-0331-466781

#### Netherlands - Drunen

Tel: 31-416-690399  
Fax: 31-416-690340

#### Spain - Madrid

Tel: 34-91-708-08-90  
Fax: 34-91-708-08-91

#### UK - Wokingham

Tel: 44-118-921-5869  
Fax: 44-118-921-5820